NSN 5961-01-128-6786

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-128-6786 Inclosure Material:

Plastic

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 repetitive peak reverse voltage

Current Rating Per Characteristic:

1.00 amperes forward current, average absolute

Power Rating Per Characteristic:

3.2 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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